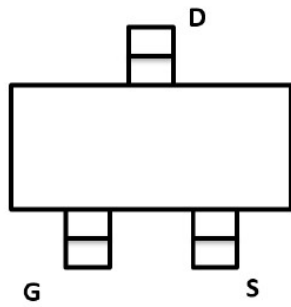
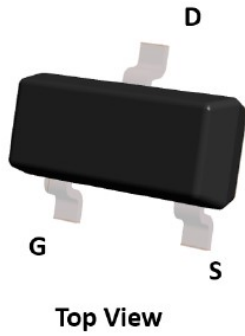
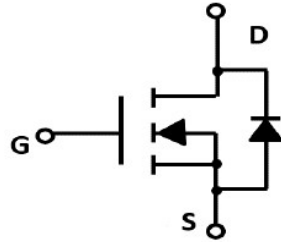


## N-Channel Enhancement Mode Field Effect Transistor



**SOT-23**



### Product Summary

- $V_{DS}$  20V
- $I_D$  4.5A
- $R_{DS(ON)}$ ( at  $V_{GS}=4.5V$ ) <25mohm
- $R_{DS(ON)}$ ( at  $V_{GS}=2.5V$ ) <32mohm
- $R_{DS(ON)}$ ( at  $V_{GS}=1.8V$ ) <46mohm
- 100%  $\nabla V_{DS}$  Tested

### General Description

- Trench Power MV MOSFET technology
- High Power and current handling capability

### Applications

- PWM application
- Load switch

### ■ Absolute Maximum Ratings ( $T_A=25^\circ C$ unless otherwise noted)

| Parameter   |                  | Symbol          | Limit    | Unit         |
|---|------------------|-----------------|----------|--------------|
| Drain-source Voltage                                |                  | $V_{DS}$        | 20       | V            |
| Gate-source Voltage                                 |                  | $V_{GS}$        | $\pm 10$ | V            |
| Drain Current                                       | $T_A=25^\circ C$ | $I_D$           | 4.5      | A            |
|   | $T_A=70^\circ C$ |                 | 3.6      |              |
| Pulsed Drain Current <sup>A</sup>                   |                  | $I_{DM}$        | 18       | A            |
| Total Power Dissipation                             | $T_A=25^\circ C$ | $P_D$           | 1        | W            |
|   | $T_A=70^\circ C$ |                 | 0.6      |              |
| Thermal Resistance Junction-to-Ambient <sup>B</sup> |                  | $R_{\theta JA}$ | 125      | $^\circ C/W$ |
| Junction and Storage Temperature Range              |                  | $T_J, T_{STG}$  | -55~+150 | $^\circ C$   |

### ■ Ordering Information (Example)

| PREFERRED P/N | PACKING CODE | Marking | MINIMUM PACKAGE(pcs) | INNER BOX QUANTITY(pcs) | OUTER CARTON QUANTITY(pcs) | DELIVERY MODE |
|---------------|--------------|---------|----------------------|-------------------------|----------------------------|---------------|
| ZXL2300A      | F2           | S0.     | 3000                 | 30000                   | 120000                     | 7" reel       |

# ZXL2300A

## ■ Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)

| Parameter                         | Symbol              | Conditions  | Min  | Typ  | Max  | Units |
|-----------------------------------|---------------------|---|------|------|------|-------|
| <b>Static Parameter</b>           |                     |   |      |      |      |       |
| Drain-Source Breakdown Voltage    | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V, I <sub>D</sub> =250μA  | 20   |      |      | V     |
| Zero Gate Voltage Drain Current   | I <sub>DSS</sub>    | V <sub>DS</sub> =20V, V <sub>GS</sub> =0V   |      |      | 1    | μA    |
| Gate-Body Leakage Current         | I <sub>GSS1</sub>   | V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V  |      |      | ±100 | nA    |
| Gate Threshold Voltage            | V <sub>GS(th)</sub> | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA                                | 0.45 | 0.62 | 1.0  | V     |
| Static Drain-Source On-Resistance | R <sub>DS(on)</sub> | V <sub>GS</sub> =4.5V, I <sub>D</sub> =4.5A   |      | 19.5 | 25   | mΩ    |
|                                   |                     | V <sub>GS</sub> =2.5V, I <sub>D</sub> =3.0A   |      | 25   | 32   |       |
|                                   |                     | V <sub>GS</sub> =1.8V, I <sub>D</sub> =2.7A   |      | 33   | 46   |       |
| Diode Forward Voltage             | V <sub>SD</sub>     | I <sub>S</sub> =4.5A, V <sub>GS</sub> =0V   |      |      | 1.2  | V     |
| <b>Dynamic Parameters</b>         |                     |   |      |      |      |       |
| Input Capacitance                 | C <sub>iss</sub>    | V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHZ                                       |      | 418  |      | pF    |
| Output Capacitance                | C <sub>oss</sub>    |   |      | 82   |      |       |
| Reverse Transfer Capacitance      | C <sub>rss</sub>    |   |      | 70   |      |       |
| <b>Switching Parameters</b>       |                     |   |      |      |      |       |
| Total Gate Charge                 | Q <sub>g</sub>      | V <sub>GS</sub> =4.5V, V <sub>DS</sub> =10V, I <sub>D</sub> =4.5A                       |      | 6.05 |      | nC    |
| Gate-Source Charge                | Q <sub>gs</sub>     |   |      | 1.07 |      |       |
| Gate-Drain Charge                 | Q <sub>gd</sub>     |   |      | 1.95 |      |       |
| Reverse Recovery Charge           | Q <sub>rr</sub>     | I <sub>F</sub> =4.5A, di/dt=100A/us   |      | 1.38 |      | ns    |
| Reverse Recovery Time             | t <sub>rr</sub>     |   |      | 17.9 |      |       |
| Turn-on Delay Time                | t <sub>D(on)</sub>  | V <sub>GS</sub> =4.5V, V <sub>DS</sub> =10V, R <sub>L</sub> =1Ω<br>R <sub>GEN</sub> =3Ω |      | 4.2  |      | ns    |
| Turn-on Rise Time                 | t <sub>r</sub>      |   |      | 19.8 |      |       |
| Turn-off Delay Time               | t <sub>D(off)</sub> |   |      | 22.6 |      |       |
| Turn-off fall Time                | t <sub>f</sub>      |   |      | 23.2 |      |       |

A. Pulse Test: Pulse Width ≤ 300us, Duty cycle ≤ 2%.

B. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>θJC</sub> is guaranteed by design, while R<sub>θJA</sub> is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.

## ■ Typical Performance Characteristics

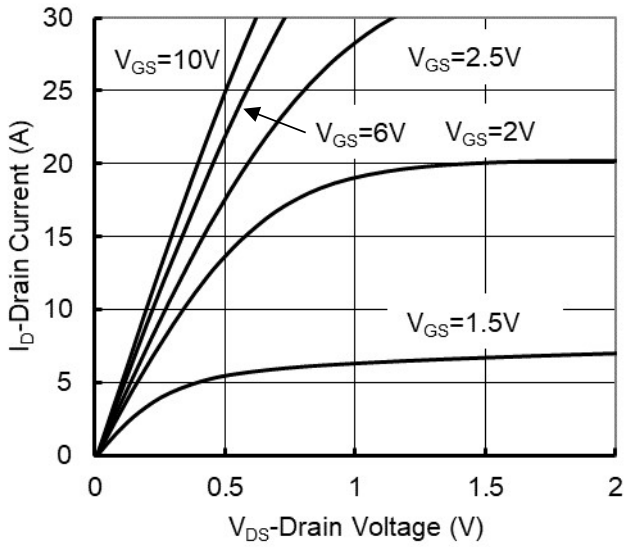


Figure1. Output Characteristics

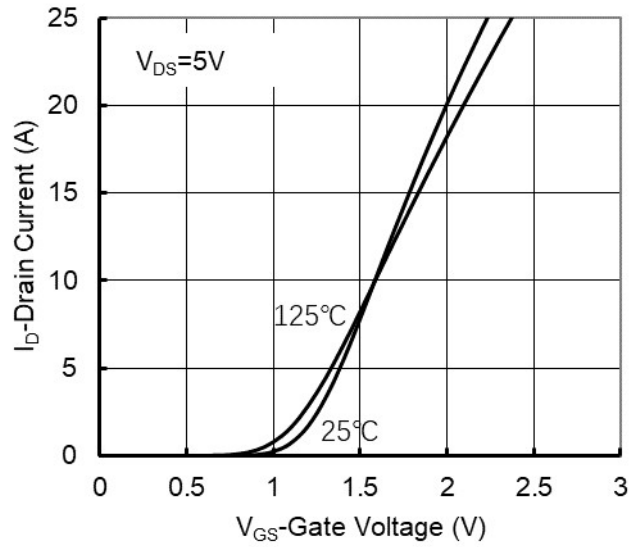


Figure2. Transfer Characteristics

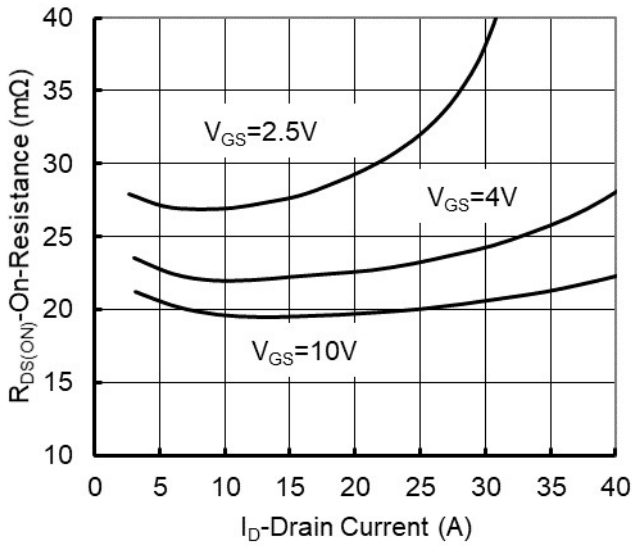


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

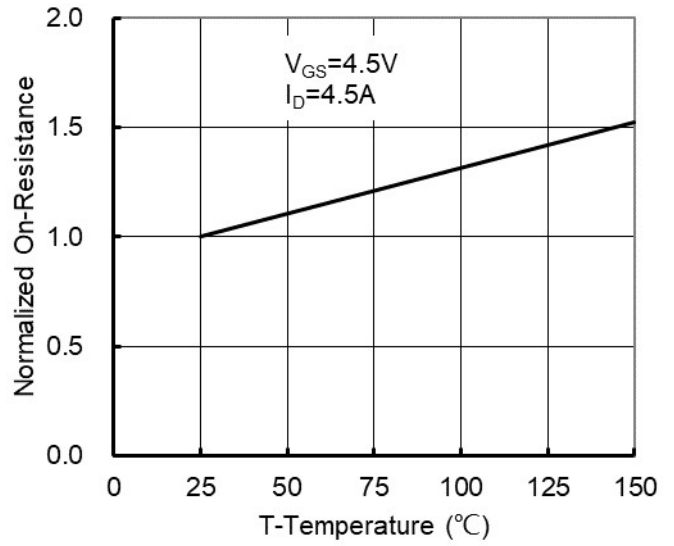


Figure 4: On-Resistance vs. Junction Temperature

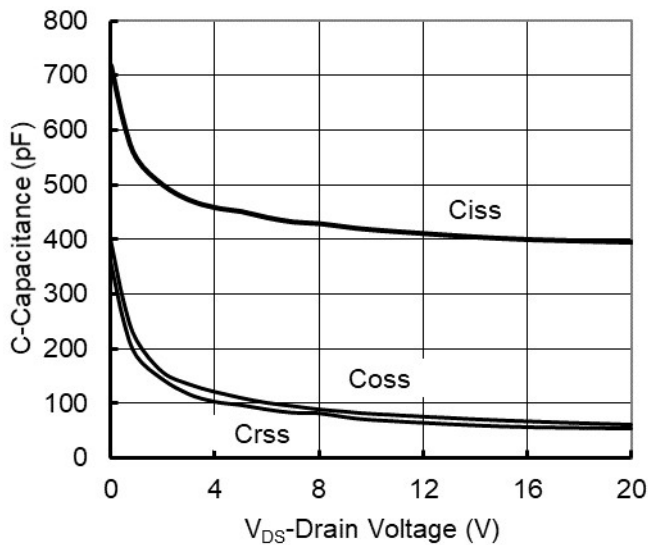


Figure5. Capacitance Characteristics

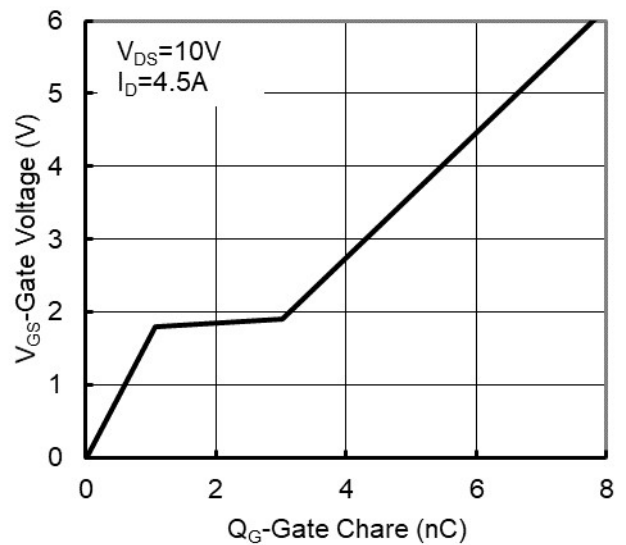


Figure6. Gate Charge

# ZXL2300A

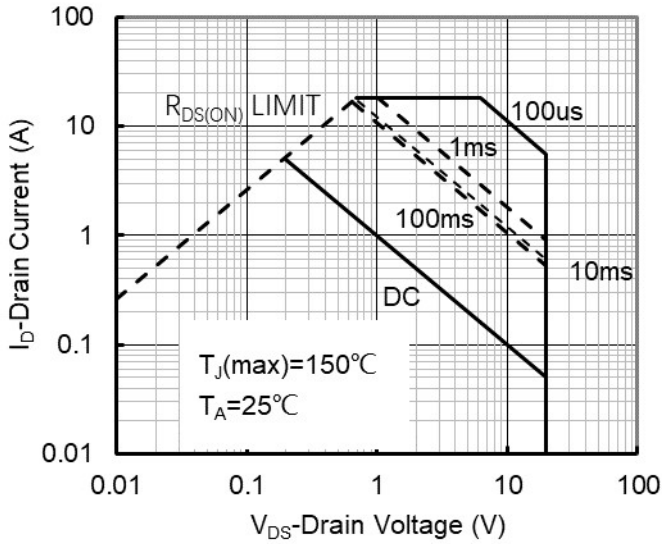


Figure7. Safe Operation Area

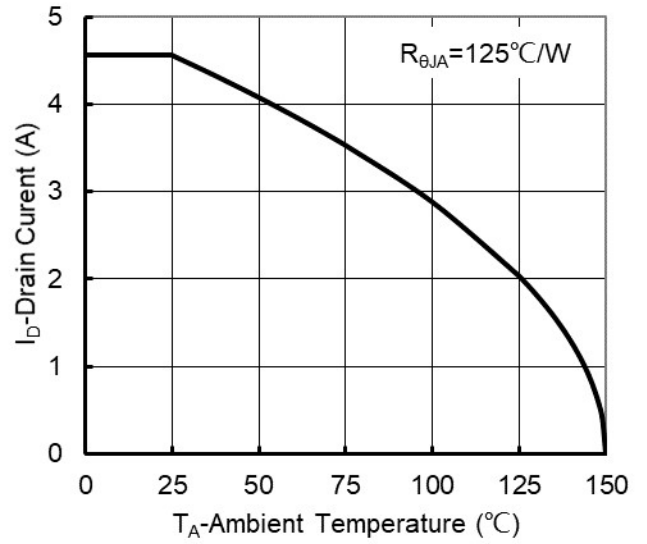


Figure8. Maximum Continuous Drain Current vs Ambient Temperature

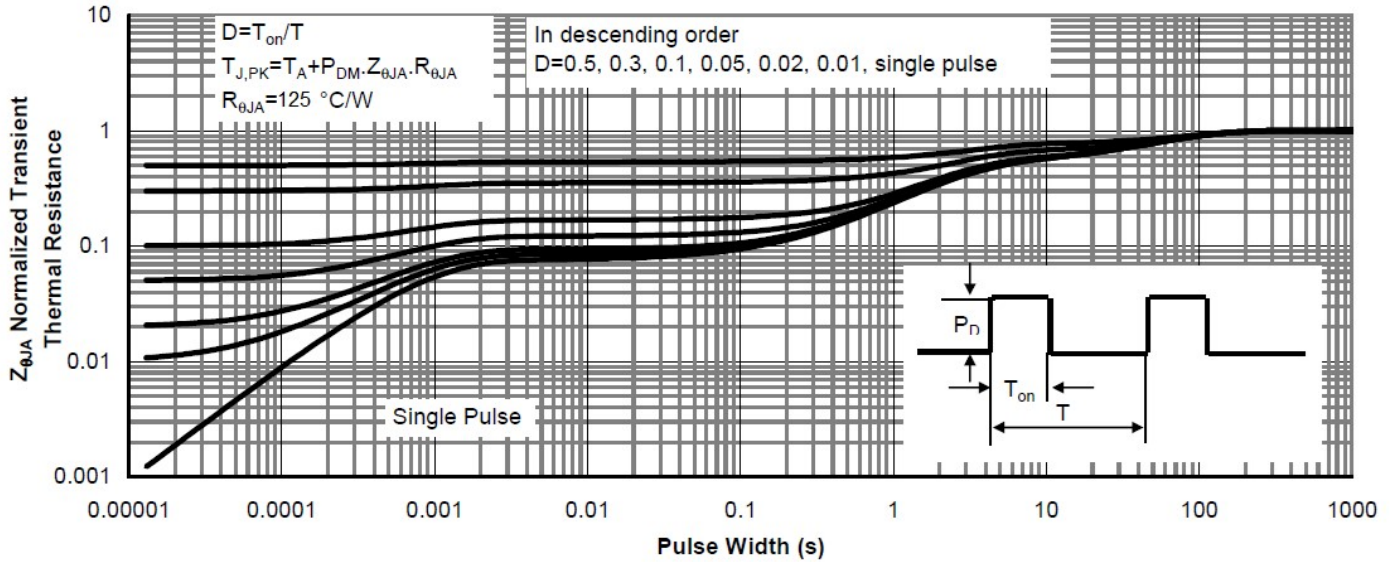
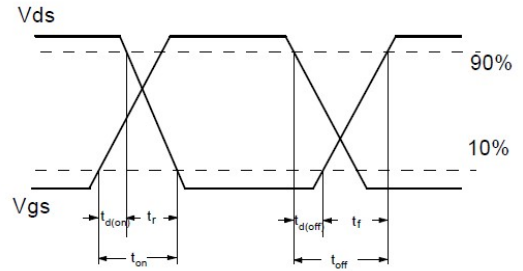
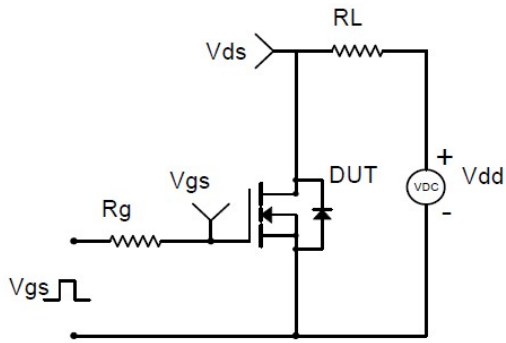
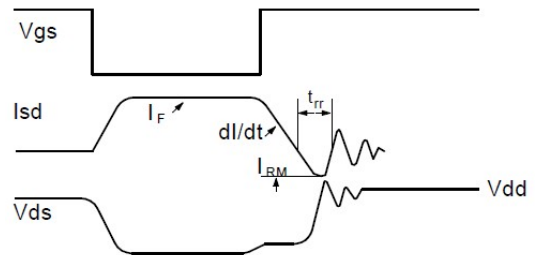
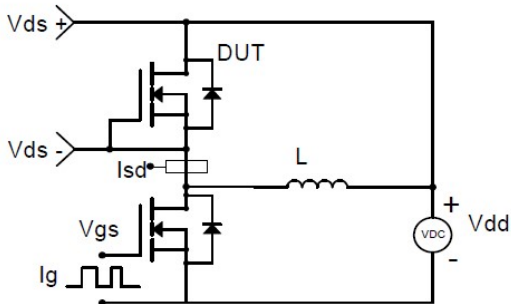


Figure9. Normalized Maximum Transient Thermal Impedance

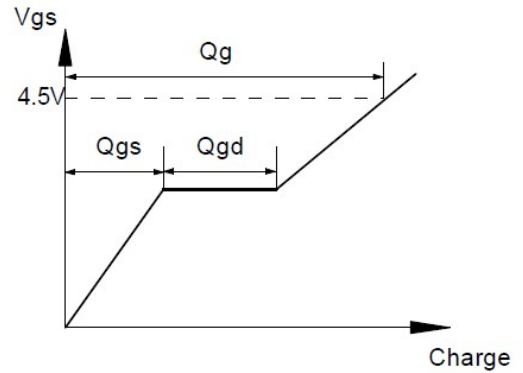
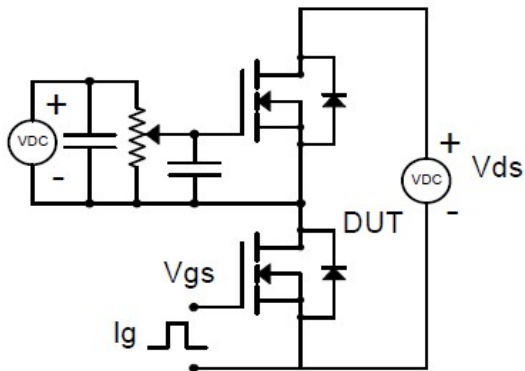
# ZXL2300A



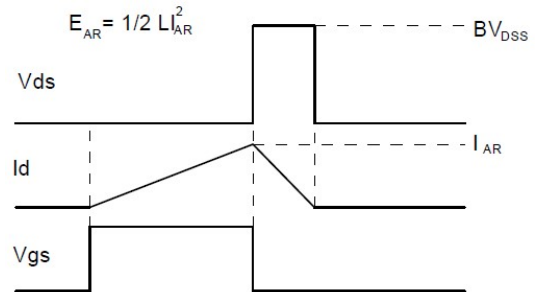
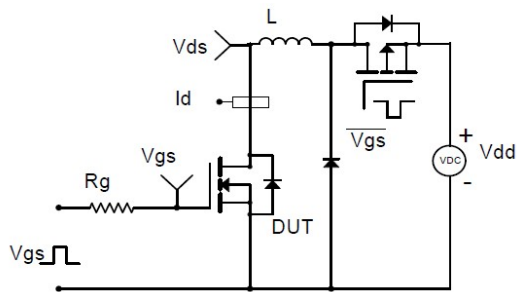
**Resistive Switching Test Circuit & Waveforms**



**Diode Recovery Test Circuit & Waveforms**



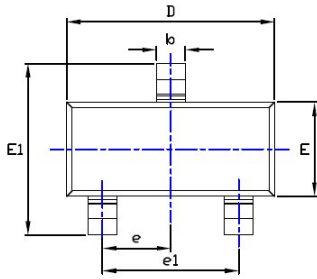
**Gate Charge Test Circuit & Waveform**



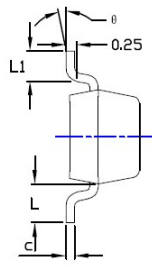
**Unclamped Inductive Switching (UIS) Test Circuit & Waveforms**

# ZXL2300A

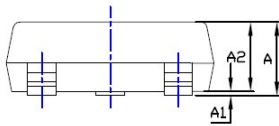
## ■ SOT-23 Package information



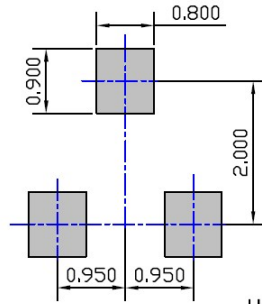
TOP VIEW



SIDE VIEW



SIDE VIEW



UNIT: mm

SUGGESTED SOLDER PAD LAYOUT

| SYMBOL | DIMENSIONS |       |       |            |       |       |
|--------|------------|-------|-------|------------|-------|-------|
|        | INCHES     |       |       | Millimeter |       |       |
|        | MIN.       | NOM.  | MAX.  | MIN.       | NOM.  | MAX.  |
| A      | 0.035      | ---   | 0.045 | 0.900      | ---   | 1.150 |
| A1     | 0.000      | ---   | 0.004 | 0.000      | ---   | 0.100 |
| A2     | 0.035      | 0.038 | 0.041 | 0.900      | 0.975 | 1.050 |
| b      | 0.012      | 0.016 | 0.020 | 0.300      | 0.400 | 0.500 |
| c      | 0.004      | ---   | 0.008 | 0.100      | ---   | 0.200 |
| D      | 0.110      | 0.114 | 0.118 | 2.800      | 2.900 | 3.000 |
| E      | 0.047      | 0.051 | 0.055 | 1.200      | 1.300 | 1.400 |
| E1     | 0.089      | 0.094 | 0.100 | 2.250      | 2.400 | 2.550 |
| e      | 0.037 TYP  |       |       | 0.950 TYP  |       |       |
| e1     | 0.071      | 0.075 | 0.079 | 1.800      | 1.900 | 2.000 |
| L      | 0.022 REF  |       |       | 0.550 REF  |       |       |
| L1     | 0.012      | 0.016 | 0.200 | 0.300      | 0.400 | 0.500 |
| θ      | 0°         | ---   | 8°    | 0°         | ---   | 8°    |

NOTE:

1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
2. TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
3. THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.